SunLike

S1S0-3030xx9503-00000000-00003 - Mid-Power LED

Actualize a spectrum closest to the sunlight

Mid-Power LED – 3030 Series

STWSC12S-E2H10000

S1S0-3030xx9503-00000000-00003



Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension.
 Package Size : 3.0x3.0x0.75mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

Thermally Enhanced Package Design

LM-80

RoHS

- Mid Power to up to 0.3W
- Max. Driving Current 100mA
- Compact Package Size
- High Color Quality with CRI Min.95 (R9>85)
- Pb-free Reflow Soldering Application

Key Applications

- Replacement lamps Bulb, Tube
- Commercial
- Industrial
- Residential

Table 1. Product Selection Table

Part Number	Color	Nominal CCT	Part Number	CRI
	00101		Fait Nullibei	Min
		6500K	S1S0-3030659503-00000000-00003	
	Cool White	5700K	S1S0-3030579503-00000000-00003	
STWSC12S-		5000K	S1S0-3030509503-00000000-00003	05
E2H10000	Neutral White	4000K	S1S0-3030409503-00000000-00003	95
	Warm White	3500K	S1S0-3030359503-00000000-00003	
		3000K	S1S0-3030309503-00000000-00003	
		2700K	S1S0-3030279503-00000000-00003	



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SunLike Performance Characteristics

Min.	Nominal	Min. Flux	Тур.	Тур.	PPF	PPE
wiin.	Nominai		Luminous	Luminous	PPP	PPE
0.01	ССТ [К] [1]	Fire 1	Flux Φ _V ^[2]	Efficacy	[µmol/s] ^[3]	[µmol/J] ^[4]
CRI		[lm]	[lm]	[lm/W]	Тур.	Тур.
	6500	24.5	26.1	136.5	0.43	2.23
	5700	24.5	26.0	135.5	0.43	2.22
	5000	24.5	26.7	138.8	0.44	2.28
95	4000	23.1	25.3	131.7	0.42	2.16
	3500	22.8	24.9	129.6	0.41	2.13
	3000	21.2	23.1	119.9	0.38	1.98
	2700	21.2	22.4	116.6	0.37	1.92

Table 2. Product Selection Guide, $I_{\rm F}$ = 65mA , $T_{\rm j}$ = 25°C, RH30%

Notes :

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 5\%$ on luminous flux.
- (3) Photosynthetic Photon Flux (PPF) includes wavelengths between 400 and 700 nm.
- (4) Photosynthetic Photon Efficacy (PPE) includes wavelengths between 400 and 700 nm.

SunLike S1S0-3030xx9503-0000000-00003 - Mid-Power LED Performance Characteristics

Table 3. Characteristics, I_F=65mA, T_i= 25°C

Parameter	Sumbol	Value			Unit
Farameter	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage ^[1]	V _F	2.80	2.96	3.10	V
Luminous Flux ^[1]	Φ_{v}	-	26.7	-	lm
Correlated Color Temperature	ССТ	2,700	-	6,500	к
CRI ^[1]	Ra	95	-	-	-
Viewing Angle ^[2]	2Θ _{1/2}	-	120	-	deg.
Thermal resistance (J to S) ^[3]	Rθ _{j-s}	-	8.0	-	K/W
ESD Sensitivity(HBM)	-	Class 3	A JESD22-A1	14-E	

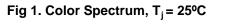
Table 4. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I _F	100	mA
Power Dissipation	P _D	0.3	W
Junction Temperature	Tj	125	°C
Operating Temperature	T _{opr}	-40 ~ + 85	°C
Storage Temperature	T _{stg}	-40 ~ + 100	٥C

Notes :

- (1) Tolerance : VF : ±0.1V, Flux : ±5%, Ra : ±2, x,y : ±0.005
- (2) $2\Theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity.
- (3) Thermal resistance : Rth_{JS} (Junction / solder)
- (4) It is recommended to use it in the condition that the reliability is secured within the Max value.
- LED's properties might be different from suggested values like above and below tables if operation condition will be exceeded our parameter range. Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.
- All measurements were made under the standardized environment of Seoul Semiconductor.

SunLike Characteristics Graph



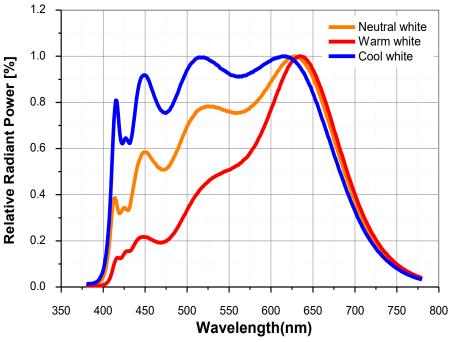
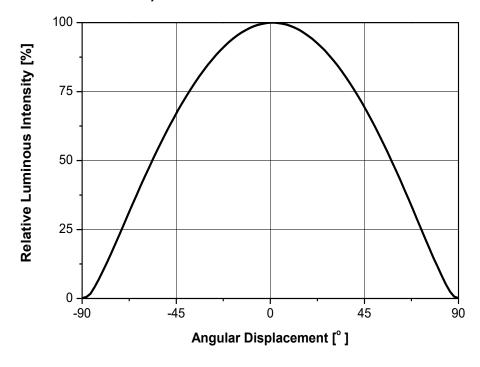


Fig 2. Radiant Pattern, T_i = 25°C



SunLike Characteristics Graph

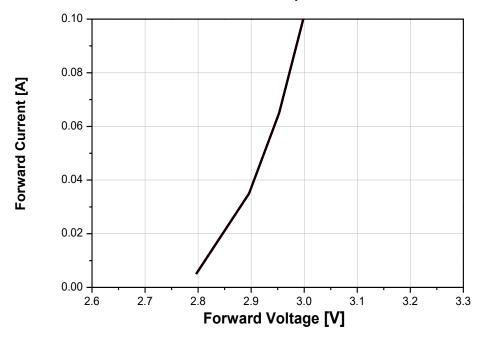
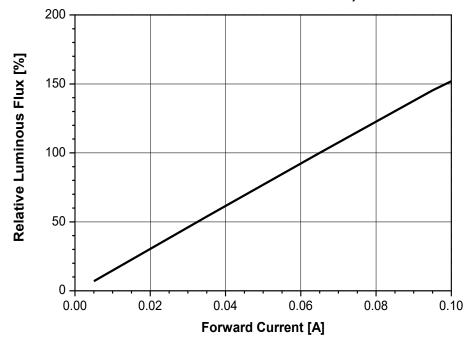
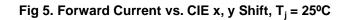


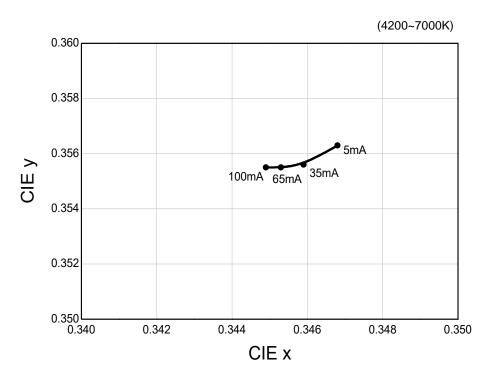
Fig 3. Forward Voltage vs. Forward Current, $T_j = 25^{\circ}C$

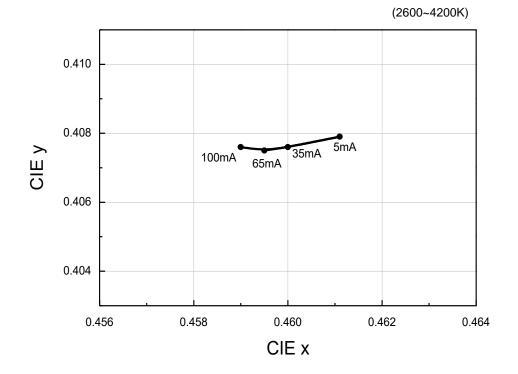




SunLike Characteristics Graph





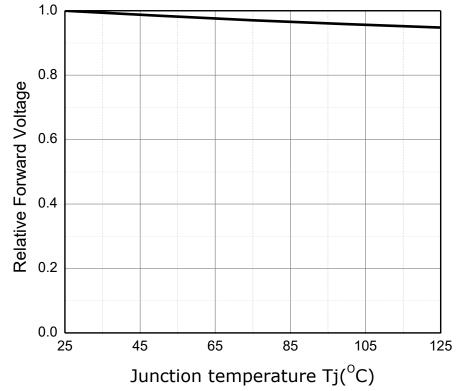


SunLike S1S0-3030xx9503-0000000-00003 - Mid-Power LED **Characteristics Graph**

> 1.0 0.8 **Relative Luminous Flux** 0.6 0.4 0.2 0.0 45 65 85 105 25 125 Junction temperature Tj(^oC)







SunLike Characteristics Graph

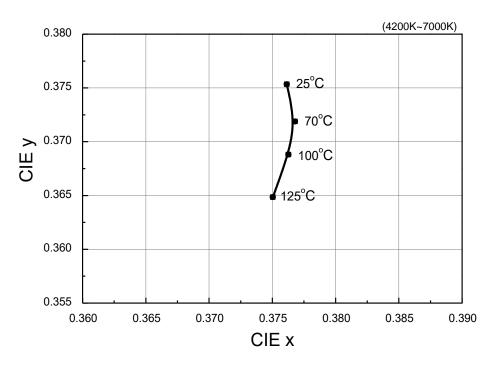
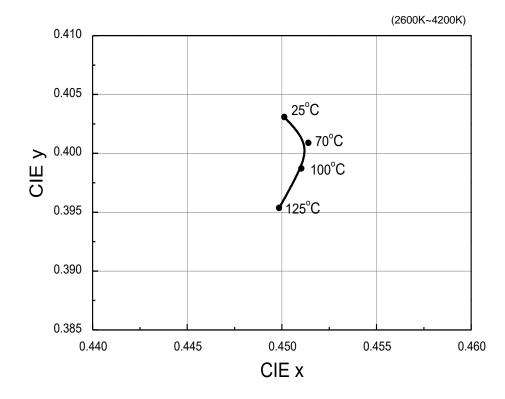
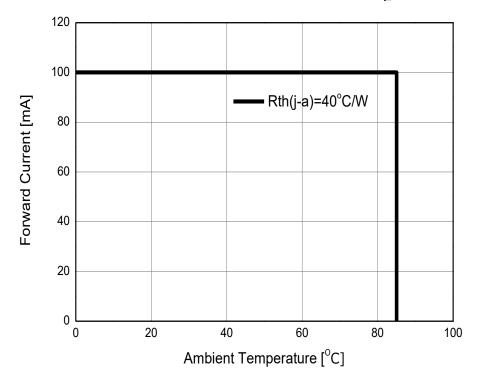


Fig 8. Chromaticity Coordinate vs. Junction Temperature, I_F=65mA



SunLike Characteristics Graph

Fig 9. Ambient Temperature vs. Maximum Forward Current, $T_{j_{max}}$ = 125°C



SunLike Color Bin Structure

Table 5. Bin Code description, $T_j=25^{\circ}C$, $I_F=65mA$

Part Number	Luminous Flux (lm)			Color Chromaticity	Typical Forward Voltage (V)		
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.
	P5	21.2	22.8		Y2	2.8	2.9
	Q0	22.8	24.5	Refer to page. 12 ~ 14			
STWSC12S- E2H10000	Q5	24.5	26.1		Y3	2.9	3.0
	R0	26.1	27.7		Z1	3.0	3.1
	R5	27.7	29.4	- -			

Table 6. Intensity rank distribution

Available ranks

сст	CIE			Flux Rank		
6000 ~ 7000K	А	P5	Q0	Q5	R0	R5
5300 ~ 6000K	В	P5	Q0	Q5	R0	R5
4700 ~ 5300K	С	P5	Q0	Q5	R0	R5
3700 ~ 4200K	E	P5	Q0	Q5	R0	R5
3200 ~ 3700K	F	P5	Q0	Q5		
2900 ~ 3200K	G	P5	Q0	Q5		
2600 ~ 2900K	н	P5	Q0	Q5		

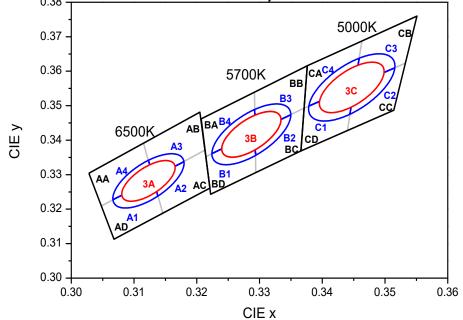
*Notes :

• All measurements were made under the standardized environment of Seoul Semiconductor. In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

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CIE Chromaticity Diagram (Cool white), $T_j=25^{\circ}C$, $I_F=65mA$



6500	K 3Step	5700	K 3Step	5000K 3Step		
	3A		3B		3 C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0067	Major Axis a	0.0075	Major Axis a	0.0082	
Minor Axis b	0.0029	Minor Axis b	0.0032	Minor Axis b	0.0035	
Ellipse Rotation Angle	59	Ellipse 59 Rotation Angle		Ellipse Rotation Angle	60	

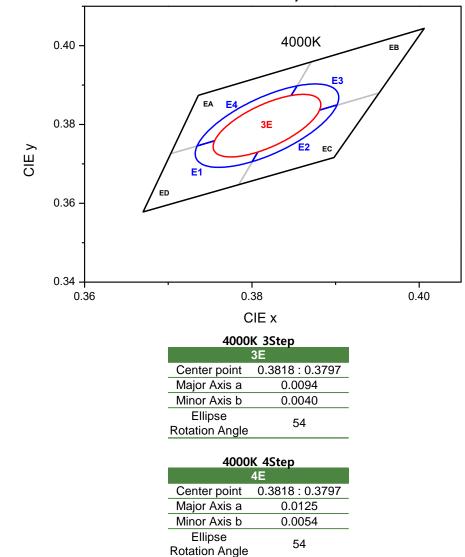
	500K 4Step 5700K 4Step 4A 4B			5000K 4Step 4C		
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0089	Major Axis a	0.0100	Major Axis a	0.0110	
Minor Axis b	0.0038	Minor Axis b	0.0043	Minor Axis b	0.0047	
Ellipse Rotation Angle	59	Ellipse Rotation Angle	59	Ellipse Rotation Angle	60	

A	Α	A	В	A	С	A	D
CIE X	CIE Y						
0.3028	0.3304	0.3115	0.3393	0.3131	0.3290	0.3048	0.3209
0.3048	0.3209	0.3131	0.3290	0.3146	0.3187	0.3068	0.3113
0.3131	0.3290	0.3213	0.3371	0.3221	0.3261	0.3146	0.3187
0.3115	0.3393	0.3205	0.3481	0.3213	0.3371	0.3131	0.3290
В	Α	В	B	В	C	В	D
CIE X	CIE Y						
0.3207	0.3462	0.3292	0.3539	0.3293	0.3423	0.3215	0.3353
0.3215	0.3353	0.3293	0.3423	0.3294	0.3306	0.3222	0.3243
0.3293	0.3423	0.3371	0.3493	0.3366	0.3369	0.3294	0.3306
0.3292	0.3539	0.3376	0.3616	0.3371	0.3493	0.3293	0.3423
C	A	C	B	C	C	C	D
CIE X	CIE Y						
0.3376	0.3616	0.3463	0.3687	0.3452	0.3558	0.3371	0.3493
0.3371	0.3493	0.3452	0.3558	0.3440	0.3428	0.3366	0.3369
0.3452	0.3558	0.3533	0.3624	0.3514	0.3487	0.3440	0.3428
0.3463	0.3687	0.3551	0.3760	0.3533	0.3624	0.3452	0.3558

Color Bin Structure

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CIE Chromaticity Diagram (Neutral white), $T_i=25^{\circ}C$, $I_F=65mA$

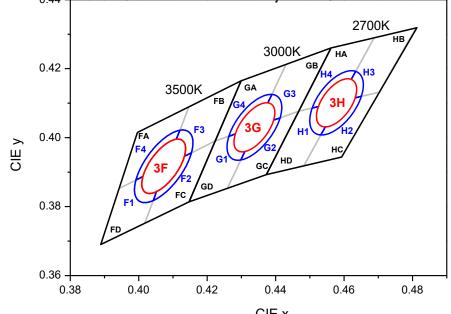


E	A	E	В	E	С	E	D
CIE X	CIE Y						
0.3736	0.3874	0.3871	0.3959	0.3828	0.3803	0.3703	0.3726
0.3703	0.3726	0.3828	0.3803	0.3784	0.3647	0.3670	0.3578
0.3828	0.3803	0.3952	0.3880	0.3898	0.3716	0.3784	0.3647
0.3871	0.3959	0.4006	0.4044	0.3952	0.3880	0.3828	0.3803

Color Bin Structure

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CIE Chromaticity Diagram (Warm white), T_i=25°C, I_F=65mA



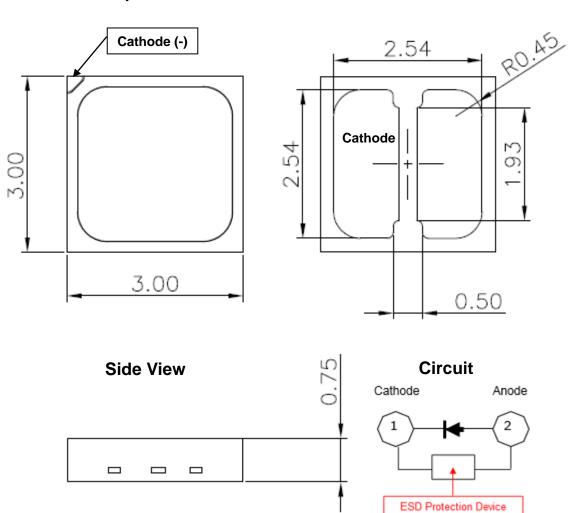
	K 3Step 3F		GEX K 3Step 3G		K 3Step 3H
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0093	Major Axis a	0.0083	Major Axis a	0.0081
Minor Axis b	0.0041	Minor Axis b	0.0041	Minor Axis b	0.0042
Ellipse 54 Rotation Angle		Ellipse Rotation Angle	53	Ellipse Rotation Angle	54

3500K 4Step 4F		3000K 4Step 4G			2700K 4Step 4H			
Center point	0.4073 :	0.3917	Center point	0.4338 : 0.4030	Center	point	0.4578 : 0.41	01
Major Axis a	0.01	24	Major Axis a	0.0112	Major /	Axis a	0.0108	
Minor Axis b	0.00	55	Minor Axis b	0.0054	Minor /	Minor Axis b		
Ellipse Rotation Angle	54		Ellipse Rotation Angle	53	Ellip Rotation		54	
FA			FB	FC			FD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE	X CIE Y	Y
0.3996	0.4015	0.414	6 0.4089	0.4082	0.3920	0.394	43 0.385	53
0.3943	0.3853	0.408	2 0.3920	0.4017	0.3751	0.388	89 0.369	3 0
0.4082	0.3920	0.422	3 0.3990	0.4147	0.3814	0.40	17 0.375	51
0.4146	0.4089	0.429	9 0.4165	0.4223	0.3990	0.408	82 0.392	20
GA			GB	GC			GD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE	X CIE	Y
0.4299	0.4165	0.443	0 0.4212	0.4345	0.4033	0.422	23 0.399) 0
0.4223	0.3990	0.434	5 0.4033	0.4259	0.3853	0.414	47 0.381	14
0.4345	0.4033	0.446	8 0.4077	0.4373	0.3893	0.42	59 0.385	53
0.4430	0.4212	0.456	2 0.4260	0.4468	0.4077	0.434	45 0.403	33
HA			HB	HC			HD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE	X CIE Y	Y
0.4562	0.4260	0.468	7 0.4289	0.4585	0.4104	0.446	68 0.407	77
0.4468	0.4077	0.458	5 0.4104	0.4483	0.3919	0.43	73 0.389) 3
0.4585	0.4104	0.470	3 0.4132	0.4593	0.3944	0.448	83 0.391	19
0.4687	0.4289	0.481	0 0.4319	0.4703	0.4132	0.458	85 0.410)4



Top View

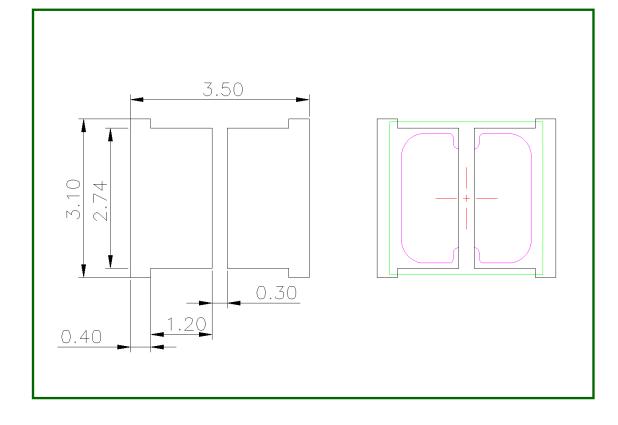
S1S0-3030xx9503-00000000-00003 - Mid-Power LED



Bottom View

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is $\pm 0.2 \text{mm}$





Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is ± 0.2 mm
- (4) This drawing without tolerances are for reference only

SunLike S1S0-3030xx9503-00000000-00003 - Mid-Power LED **Reflow Soldering Characteristics**

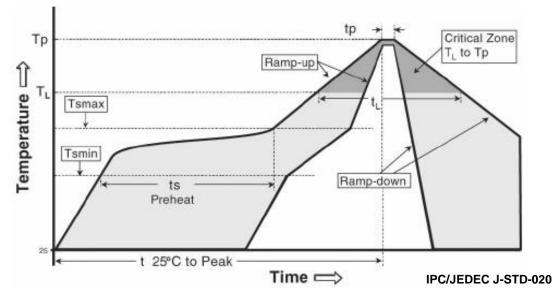


Table 7.

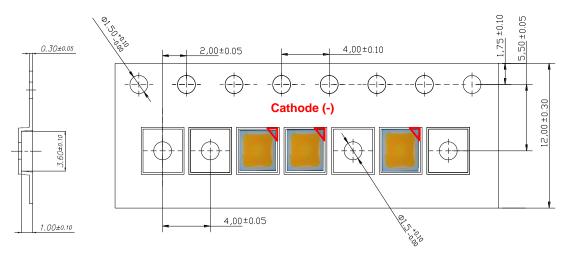
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	183 ℃ 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (Tp)	215℃	260°C
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

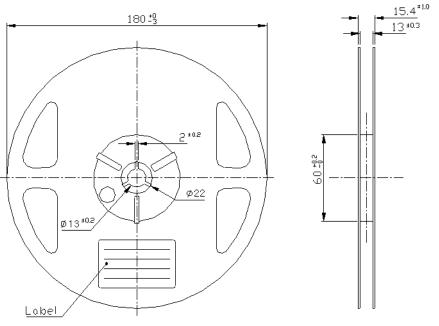
Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

Emitter Tape & Reel Packing

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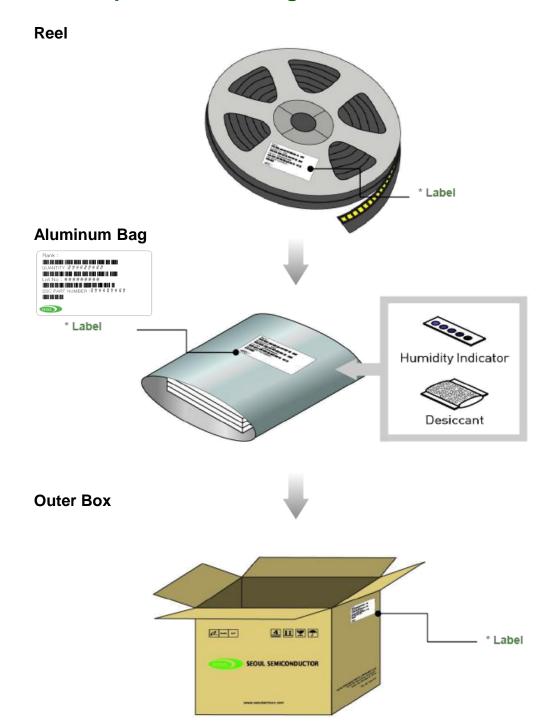


(Tolerance: ± 0.2 , Unit: mm)

- (1) Quantity: 4,000pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be \pm 0.2mm
- (3) Adhesion Strength of Cover Tape
- Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape.
- (4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

Emitter Tape & Reel Packing

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SunLike Product Nomenclature

Table 8. Part Numbering System

Part Number Code	Description	Part Number	Value
X ₁	Company	S	
X ₂	Top View LED series	т	
X ₃ X ₄	Color Specification	WS	SunLike
X ₅	Package series	С	C series
X ₆ X ₇	Characteristic code	12	
X ₈	Revision	S	
X ₉	Characteristic	E2H10000	

Order Code	Description	Order Code	Value
X ₁	Company	S	Seoul Semiconductor
X ₂	Level of Integration	1	Discrete LED
X ₃ X ₄	Technology	S0	SunLike General
X ₅ X ₆ X ₇ X ₈	Dimension	3030	3.0x3.0mm
X ₉ X ₁₀	CCT	xx	50: 5000K
X ₁₁ X ₁₂	CRI	95	CRI95
X ₁₃ X ₁₄	Vf	03	
X ₁₅ X ₁₆ X ₁₇	Characteristic code Flux Rank	000	
X ₁₈ X ₁₉ X ₂₀	Characteristic code Vf Rank	000	
X ₂₁ X ₂₂	Characteristic code Color Step	00	00 : Full 3S: 3step ellipse 4S: 4step ellipse
X ₂₃ X ₂₄	Туре	00	
X ₂₅ X ₂₆ X ₂₇	Internal code	003	Performance

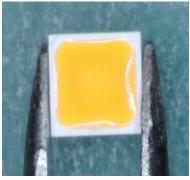
Handling of Silicone Resin for LEDs

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(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

SunLike Precaution for Use

S1S0-3030xx9503-00000000-00003 - Mid-Power LED

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant . The recommended storage temperature range is 5° C to 30° C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 40 $^\circ\!\!C$ Humidity : less than RH30%
- b. If the package has been opened more than 4 week(MSL_2a) or the color of the

desiccant changes, components should be dried for 10-12hr at $60\pm5^\circ\!C$

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

(10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor. A sealed container with a nitrogen atmosphere should be used for storage.

(11) The appearance and specifications of the product may be modified for improvement without notice.

(12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

SunLike Precaution for Use

S1S0-3030xx9503-00000000-00003 - Mid-Power LED

(13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(14) The slug is electrically isolated.

(15) Attaching LEDs, do not use adhesives that outgas organic vapor.

(16) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(17) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

SunLike Precaution for Use

S1S0-3030xx9503-00000000-00003 - Mid-Power LED

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package

(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)

- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
- (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device



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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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